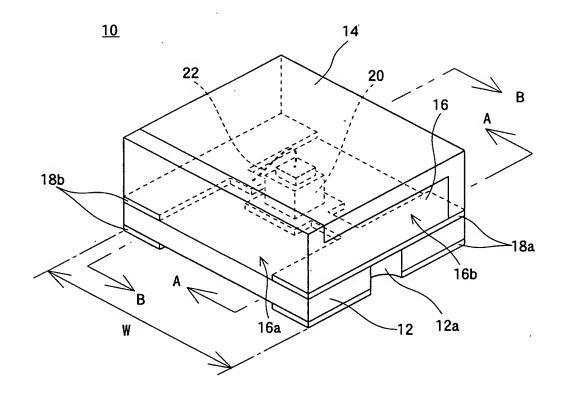
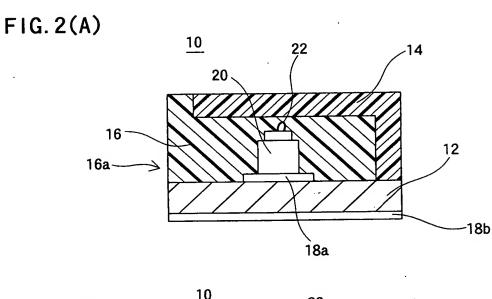
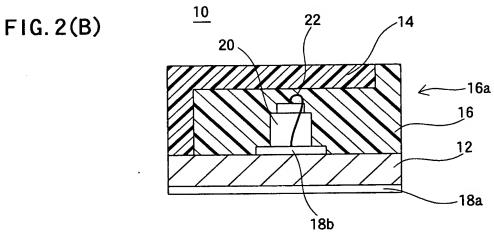
nventor: Takehiro Fujii Docket No.: 362-59 PCT/US Express Mailing No.: EL608295130 US

FIG. 1



Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method hereof ventor: Takehiro Fujii Jocket No.: 362-59 PCT/US Express Mailing No.: EL608295130 US





Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method of http://dx.doi.org/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007/10.1007

htor: Takehiro Fujii Docket No.: 362-59 PCT/US Express Mailing No.: EL608295130 US

FIG. 3(A)

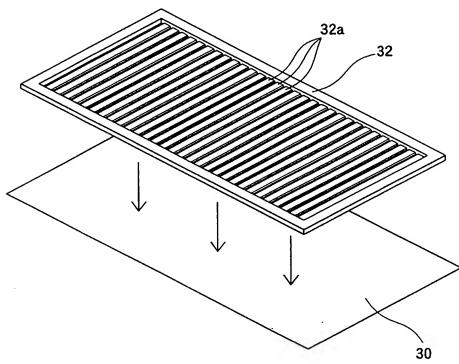
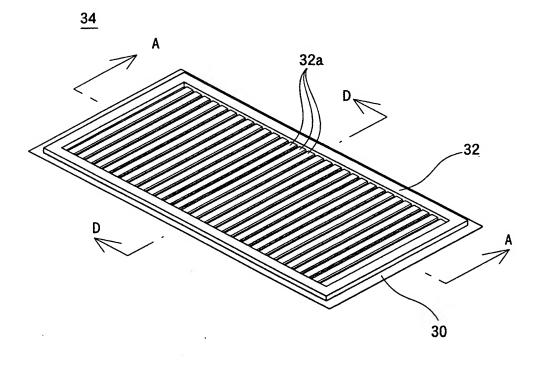
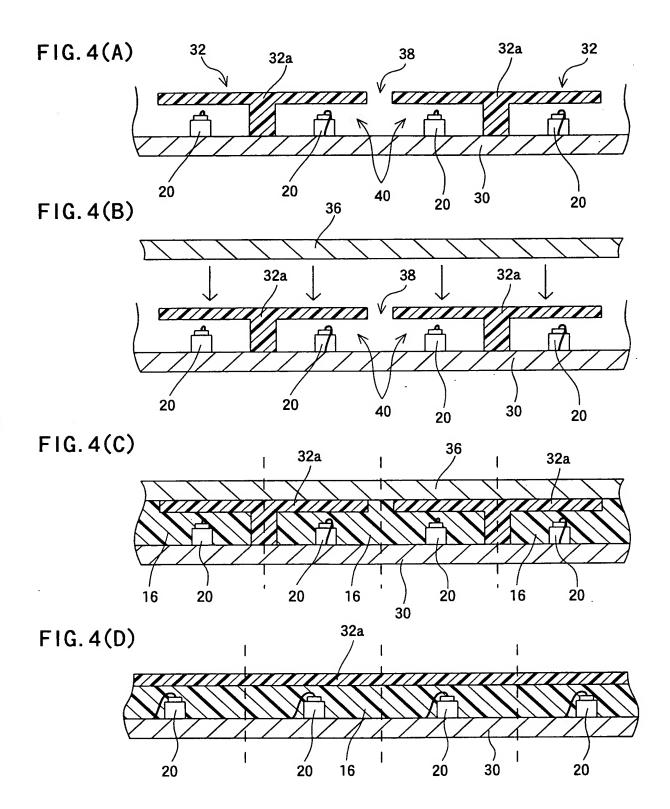


FIG. 3(B)



Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method reof htor: Takehiro Fujii ket No.: 362-59 PCT/US Express Mailing No.: EL608295130 US

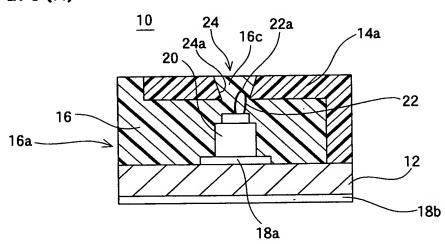


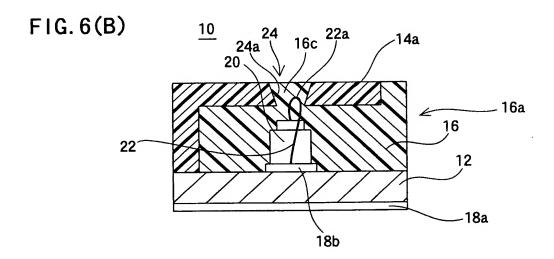
Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method ereof entor: Takehiro Fujii Docket No.: 362-59 PCT/US Express Mailing No.: EL608295130 US

FIG. 5 22a <u>10</u> 20 , - 24 14a 22、 В 18b 16 -18a 16b В 12a 16a

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FIG. 6(A)

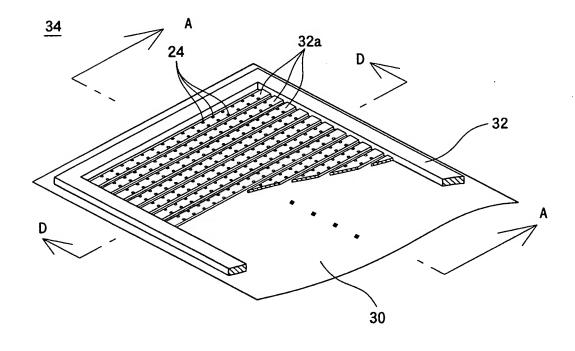




Title: Side-Emission Type Semiconductor Light-Emitting Device and Manufacturing Method Thereof Eventor: Takehiro Fujii Docket No.: 362-59 PCT/US Express Mailing No.: EL608295130 US

FIG. 7(A) 24 <u>3</u>2a 32 30

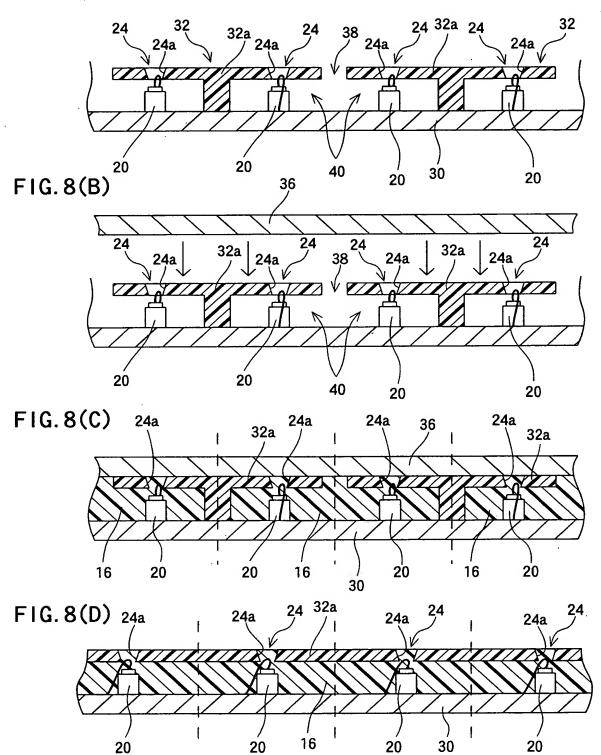
FIG. 7(B)



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FIG. 8(A)



Description: Takehiro Fujii
Description: 362-59 PCT/US
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FIG.9

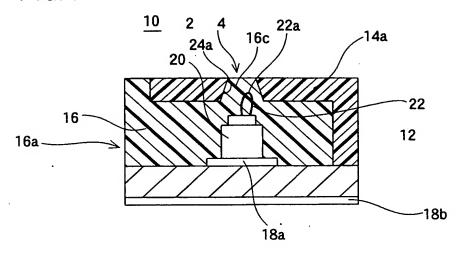
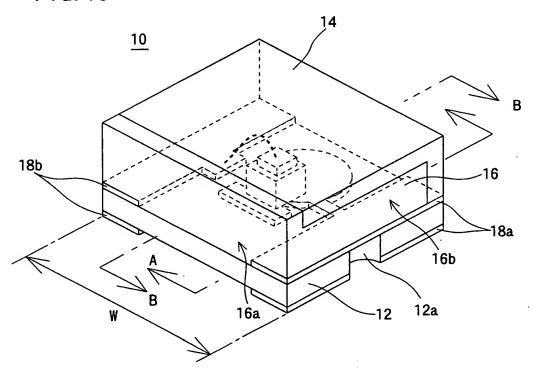


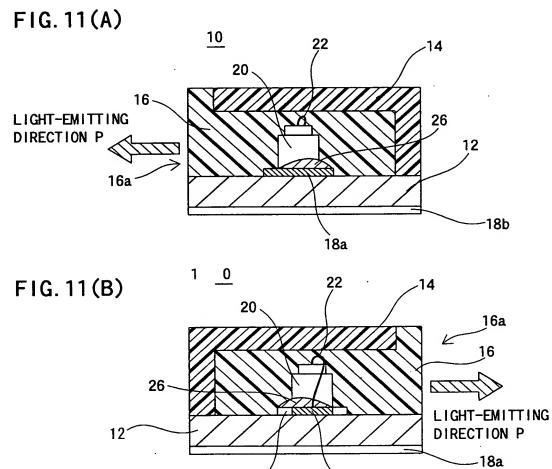
FIG. 10



reof

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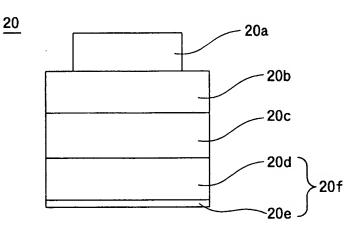


18a

FIG. 12

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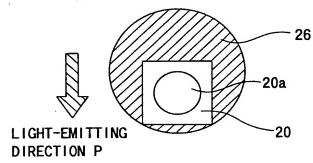
. Feb

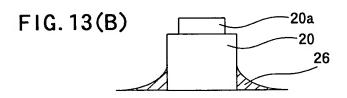


18b

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FIG. 13(A)





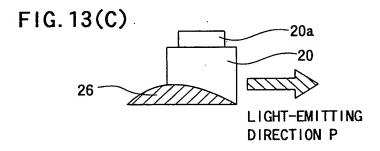


FIG. 13(D)

20a
20
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FIG. 14(A)

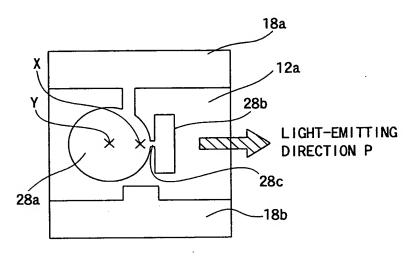
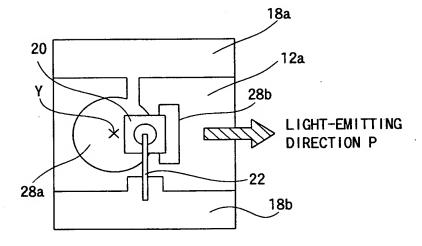


FIG. 14(B)



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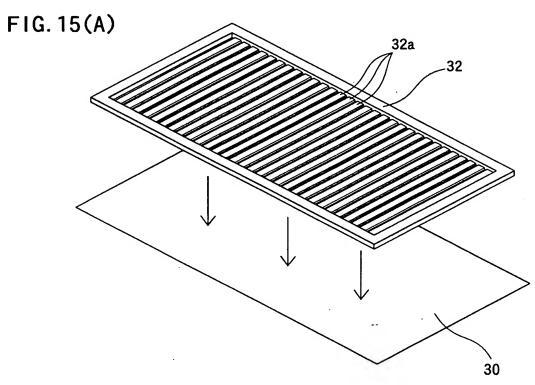
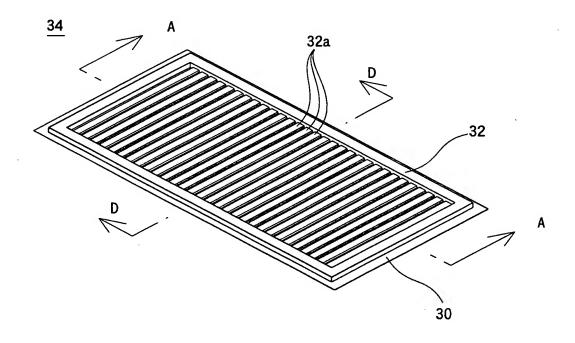
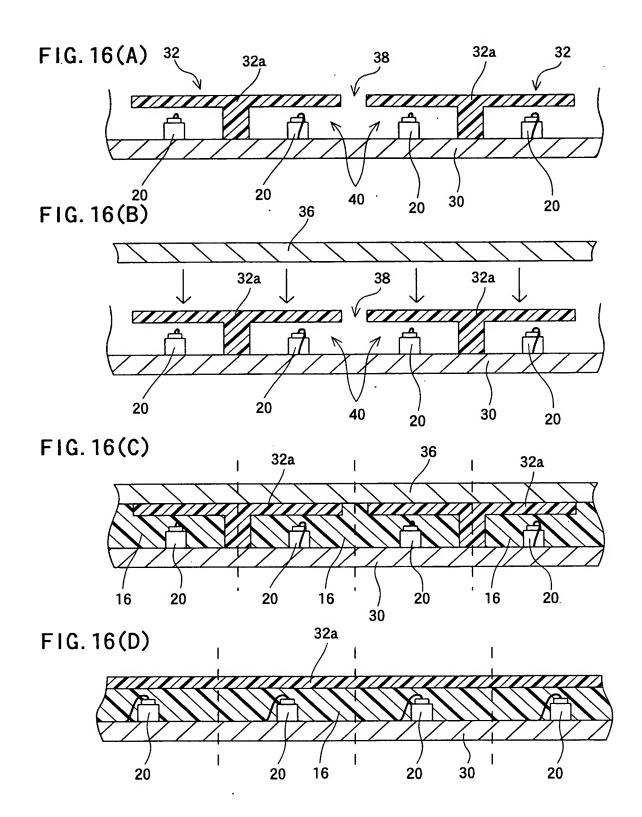


FIG. 15(B)

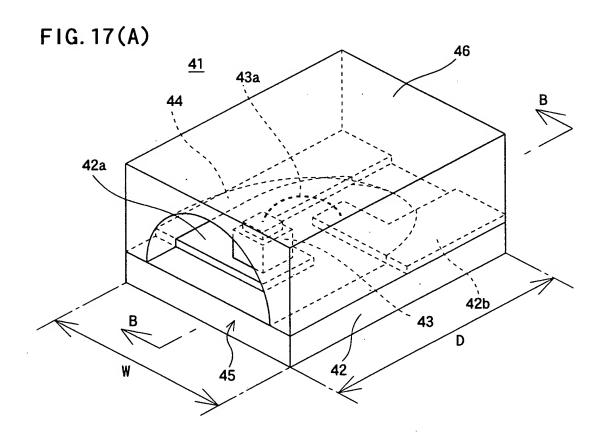


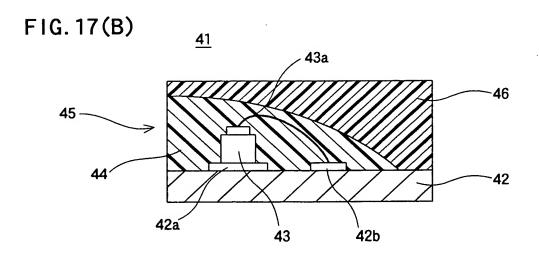
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FIG. 18(A)

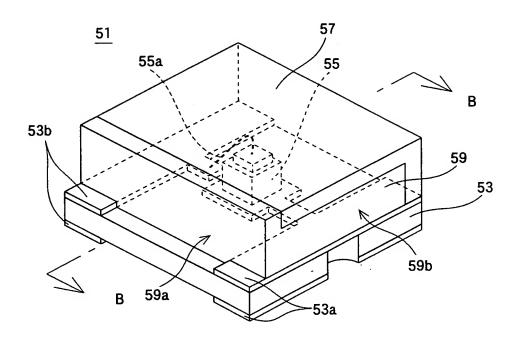
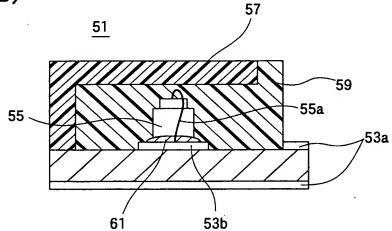


FIG. 18(B)



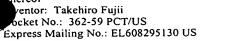
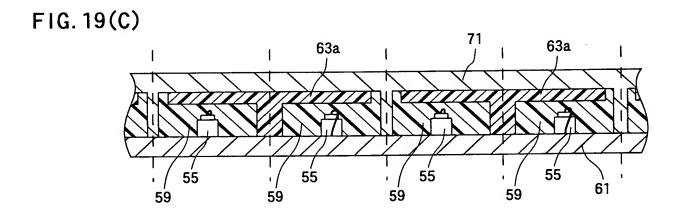




FIG. 19(A) 63 63 63a 63a 73 55 55 55 61 FIG. 19(B) 71 71a 63a 63a



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